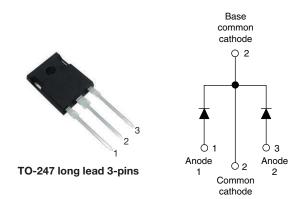
Vishay Semiconductors

Ultrafast Rectifier, 2 x 30 A FRED Pt[®]



www.vishay.com

PRODUCT SUMMARY						
Package	TO-247 long lead 3-pins					
I _{F(AV)}	2 x 30 A					
V _R	600 V					
V _F at I _F	1.75 V					
t _{rr} typ.	26 ns					
T _J max.	175 °C					
Diode variation	Common cathode					

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Designed and qualified according to commercial qualification



 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTIONS/APPLICATIONS

VS-CPU60... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	T _C = 131 °C	60				
Non-repetitive peak surge current per leg	I _{FSM}	T _J = 25 °C	250	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-			
Forward voltage	V _F	I _F = 30 A	-	1.4	1.75	V		
		$I_F = 30 \text{ A}, T_J = 150 ^{\circ}\text{C}$	-	1.1	1.4			
Devenue la classe commente	I _R	$V_{R} = V_{R}$ rated	-	0.02	30			
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	30	200	μΑ		
Junction capacitance	CT	V _R = 600 V	-	20	-	pF		



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		26	-			
Reverse recovery time	t _{rr}	$T_J = 25 \ ^\circ C$		-	42	-	ns		
		T _J = 125 °C		-	100	-			
Peak recovery current	1	T _J = 25 °C	I _F = 30 A dI _F /dt = - 200 A/μs	-	5	-	А		
	IRRM	T _J = 125 °C	$V_{\rm R} = 200 \text{ V}$	-	10	-	A		
Reverse recovery charge	0	T _J = 25 °C		-	125	-			
	Q _{rr}	T _J = 125 °C		-	580	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C		
Thermal resistance, junction to case per leg	R _{thJC}		-	0.7	1			
Thermal resistance, junction to ambient per leg	R _{thJA}	R _{thJA} Typical socket mount		-	70	°C/W		
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-			
Weight			-	6.0	-	g		
weight			-	0.21	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)		
Marking device		Case style TO-247 long lead 3-pins	CPU6006L					



VS-CPU6006L-M3

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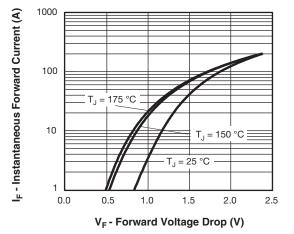


Fig. 1 - Typical Forward Voltage Drop Characteristics

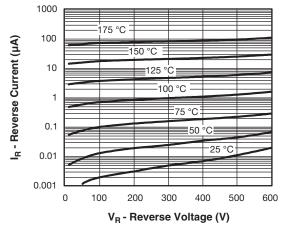


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

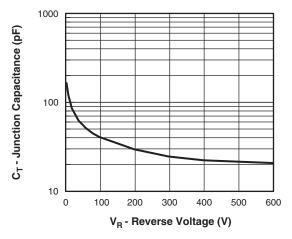


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

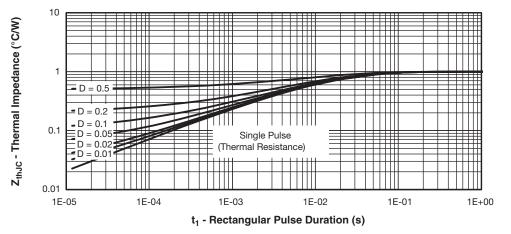
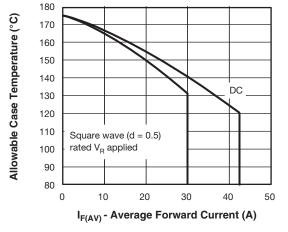
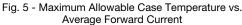


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics







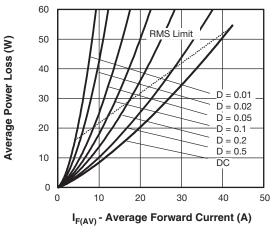


Fig. 6 - Forward Power Loss Characteristics

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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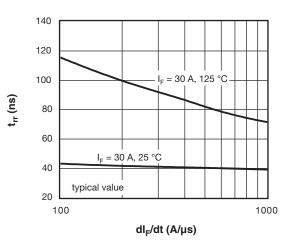


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

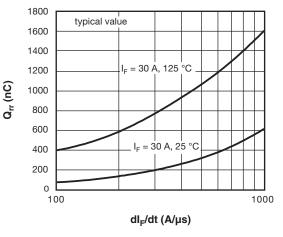


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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VS-CPU6006L-M3

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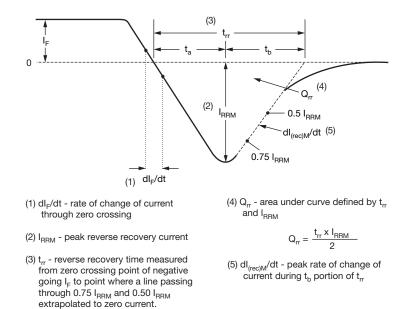


Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	VS-	с	Р	U	60	06	L	-M3
		2	3	4	5	6	7	8
	1	- Vis	hay Ser	nicondu	ctors pro	oduct		
	2			figuratio				
	_	C =	commo	on catho	de			
			TO-24					
	4			st recove	-			
	5	- Cu	rrent co	de (60 =	2 x 30 /	4)		
	6	- Vol	tage co	de (06 =	600 V)			
	7	- L=	long lea	ad				
	8	- Env	/ironme	ntal digi	t:			
		-M3	3 = halo	gen-free	, RoHS-	complia	ant and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-CPU6006L-M3	30	300	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-247 3-pins LL	www.vishay.com/doc?95599				
Part marking information	TO-247 3-pins LL	www.vishay.com/doc?95593				

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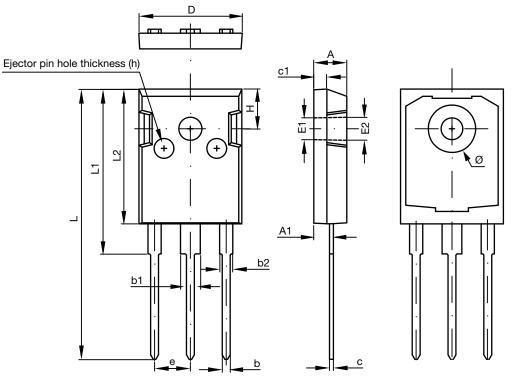
Outline Dimensions



Vishay Semiconductors

TO-247AD 3L

DIMENSIONS in millimeters



SYMBOL	DIMENSIONS I	N MILLIMETERS	DIMENSIONS IN INCHES		
STMBOL	MIN.	MAX.	MIN.	MAX.	
A	4.850	5.150	0.191	0.200	
A1	2.200	2.600	0.087	0.102	
b	1.000	1.400	0.039	0.055	
b1	2.800	3.200	0.110	0.126	
b2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.900	2.100	0.075	0.083	
D	15.450	15.750	0.608	0.620	
E1	3.50	0 Ref.	0.138	Ref.	
E2	3.60	0 Ref.	0.142 Ref.		
L	40.900	41.300	1.610	1.626	
L1	24.800	25.100	0.976	0.988	
L2	20.300	20.600	0.799	0.811	
Ø	7.100	7.300	0.280	0.287	
е	5.450	5.450 Typ.		Тур.	
Н	5.980) Тур.	0.235	Тур.	
h	0.000	0.300	0.000	0.012	

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